ON Semiconductor

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2N5457, 2N5458

JFETs - General Purpose

N-Channel - Depletion

N-Channel Junction Field Effect Transistors, depletion mode (Type A) designed for audio and switching applications.

Features

- N-Channel for Higher Gain
- Drain and Source Interchangeable
- High AC Input Impedance
- High DC Input Resistance
- Low Transfer and Input Capacitance
- Low Cross-Modulation and Intermodulation Distortion
- Plastic Encapsulated Package
- Pb-Free Packages are Available*

MAXIMUM RATINGS

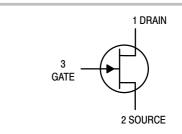
Rating	Symbol	Value	Unit
Drain-Source Voltage	V _{DS}	25	Vdc
Drain - Gate Voltage	V_{DG}	25	Vdc
Reverse Gate - Source Voltage	V_{GSR}	-25	Vdc
Gate Current	IG	10	mAdc
Total Device Dissipation @ T _A = 25°C Derate above 25°C	P _D	310 2.82	mW mW/°C
Operating Junction Temperature	TJ	135	°C
Storage Temperature Range	T _{stg}	-65 to +150	°C

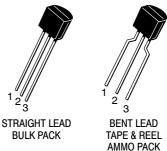
Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.



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http://onsemi.com







MARKING

TO-92 CASE 29 STYLE 5

2N545x = Device Code

x = 7 or 8

A = Assembly Location

Y = Year
WW = Work Week
■ = Pb-Free Package
(Note: Microdot may be in either location)

ORDERING INFORMATION

Device	Package	Shipping
2N5457	TO-92	1000 Units/Box
2N5457G	TO-92 (Pb-Free)	1000 Units/Box
2N5458	TO-92	1000 Units/Box
2N5458G	TO-92 (Pb-Free)	1000 Units/Box

^{*}For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

2N5457, 2N5458

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Тур	Max	Unit	
OFF CHARACTERISTICS		•		•		•
Gate – Source Breakdown Voltage ($I_G = -10 \mu Adc, V_{DS} = 0$)		V _(BR) GSS	-25	_	_	Vdc
Gate Reverse Current $ \begin{aligned} &(V_{GS} = -15 \text{ Vdc}, V_{DS} = 0) \\ &(V_{GS} = -15 \text{ Vdc}, V_{DS} = 0, T_A = 100^{\circ}\text{C}) \end{aligned} $		I _{GSS}	- -	_ _	- 1.0 -200	nAdc
Gate-Source Cutoff Voltage (V _{DS} = 15 Vdc, i _D = 10 nAdc)	2N5457 2N5458	V _{GS(off)}	-0.5 -1.0	- -	-6.0 -7.0	Vdc
Gate-Source Voltage $(V_{DS} = 15 \text{ Vdc}, i_D = 100 \mu\text{Adc})$ $(V_{DS} = 15 \text{ Vdc}, i_D = 200 \mu\text{Adc})$	2N5457 2N5458	V _{GS}	- -	-2.5 -3.5	- -	Vdc
ON CHARACTERISTICS						
Zero-Gate-Voltage Drain Current (Note 1) (V _{DS} = 15 Vdc, V _{GS} = 0)	2N5457 2N5458	I _{DSS}	1.0 2.0	3.0 6.0	5.0 9.0	mAdc
DYNAMIC CHARACTERISTICS						
Forward Transfer Admittance (Note 1) (V _{DS} = 15 Vdc, V _{GS} = 0, f = 1 kHz)	2N5457 2N5458	Y _{fs}	1000 1500	3000 4000	5000 5500	μmhos
Output Admittance Common Source (Note 1) (V _{DS} = 15 Vdc, V _{GS} = 0, f = 1 kHz)		Y _{os}	-	10	50	μmhos
Input Capacitance (V _{DS} = 15 Vdc, V _{GS} = 0, f = 1 kHz)		C _{iss}	_	4.5	7.0	pF
Reverse Transfer Capacitance (V _{DS} = 15 Vdc, V _{GS} = 0, f = 1 kHz)		C _{rss}	-	1.5	3.0	pF

^{1.} Pulse Width \leq 630 ms, Duty Cycle \leq 10%.

TYPICAL CHARACTERISTICS For 2N5457 Only

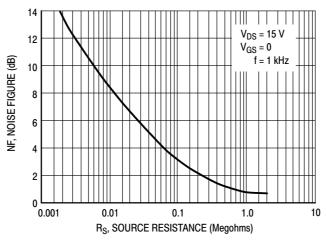


Figure 1. Noise Figure versus Source Resistance

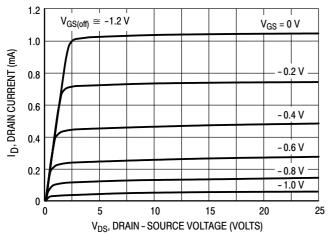


Figure 2. Typical Drain Characteristics

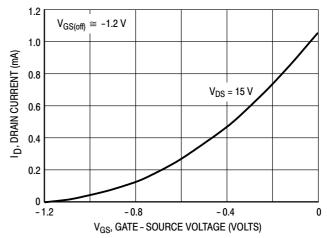


Figure 3. Common Source Transfer Characteristics

TYPICAL CHARACTERISTICS For 2N5457 Only

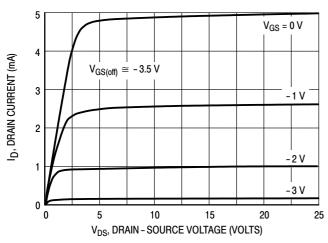
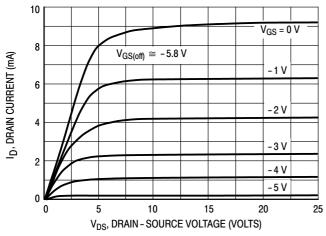


Figure 4. Typical Drain Characteristics

Figure 5. Common Source Transfer Characteristics



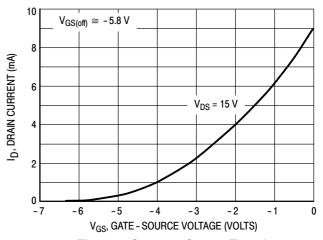
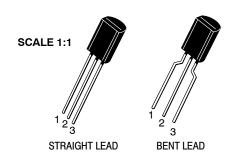


Figure 6. Typical Drain Characteristics

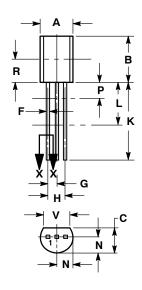
Figure 7. Common Source Transfer Characteristics

NOTE: Note: Graphical data is presented for dc conditions. Tabular data is given for pulsed conditions (Pulse Width = 630 ms, Duty Cycle = 10%). Under dc conditions, self heating in higher I_{DSS} units reduces I_{DSS} .



TO-92 (TO-226) 1 WATT CASE 29-10 **ISSUE A**

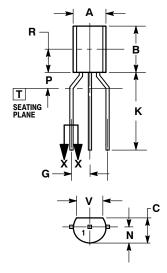
DATE 08 MAY 2012



STRAIGHT LEAD







BENT LEAD



NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI
- Y14.5M, 1994. CONTROLLING DIMENSION: INCHES.
- CONTOUR OF PACKAGE BEYOND DIMENSION R IS
- UNCONTROLLED.

 DIMENSION F APPLIES BETWEEN DIMENSIONS P

4.	DIMILI	INIOINI	ALLEILO	DLIVVI		VILIVOIC	JIVO
	AND L	. DIMEN	ISIONS D	AND J	APPLY I	BETWE	EN DI-
	MENS	IONS L	AND K MIN	MUMIK	. THE LI	EAD	
	DIMEN	ISIONS	ARE UNC	ONTRO	DLLED I	N DIME	ENSION
	P AND	BEYON	ND DIMEN	SION K	MINIM	UM.	
				1			

	INC	HES	MILLIN	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.175	0.205	4.44	5.21
В	0.290	0.310	7.37	7.87
С	0.125	0.165	3.18	4.19
D	0.018	0.021	0.46	0.53
F	0.016	0.019	0.41	0.48
G	0.045	0.055	1.15	1.39
Н	0.095	0.105	2.42	2.66
J	0.018	0.024	0.46	0.61
K	0.500		12.70	
L	0.250		6.35	
N	0.080	0.105	2.04	2.66
Р		0.100		2.54
R	0.135		3.43	
٧	0.135		3.43	
V	0.135		3.43	

- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ASME
- CONTROLLING DIMENSION: INCHES.
 CONTOUR OF PACKAGE BEYOND DIMENSION R IS
- UNCONTROLLED.
 DIMENSION F APPLIES BETWEEN DIMENSIONS P
 AND L. DIMENSIONS D AND J APPLY BETWEEN
 DIMENSIONS L AND K MINIMUM. THE LEAD DIMENSIONS ARE UNCONTROLLED IN DIMENSION P AND BEYOND DIMENSION K MINIMUM.

	INC	HES	MILLIN	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.175	0.205	4.44	5.21
В	0.290	0.310	7.37	7.87
С	0.125	0.165	3.18	4.19
D	0.018	0.021	0.46	0.53
G	0.094	0.102	2.40	2.80
J	0.018	0.024	0.46	0.61
K	0.500		12.70	
N	0.080	0.105	2.04	2.66
P		0.100		2.54
R	0.135		3.43	
٧	0.135		3.43	

STYLES ON PAGE 2

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DESCRIPTION:	TO-92 (TO-226) 1 WATT		PAGE 1 OF 2

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TO-92 (TO-226) 1 WATT CASE 29-10

ISSUE A

DATE 08 MAY 2012

STYLE 1: PIN 1. 2. 3.	EMITTER BASE COLLECTOR	STYLE 2: PIN 1. 2. 3.	BASE EMITTER COLLECTOR	STYLE 3: PIN 1. 2. 3.	ANODE ANODE CATHODE	STYLE 4: PIN 1. 2. 3.	CATHODE CATHODE ANODE	STYLE 5: PIN 1. 2. 3.	DRAIN SOURCE GATE
	GATE SOURCE & SUBSTRATE DRAIN	STYLE 7: PIN 1. 2. 3.	SOURCE DRAIN GATE	STYLE 8: PIN 1. 2. 3.	DRAIN GATE SOURCE & SUBSTRATE	STYLE 9: PIN 1. 2. 3.	BASE 1 EMITTER BASE 2	STYLE 10: PIN 1. 2. 3.	CATHODE GATE ANODE
2.	ANODE CATHODE & ANODE CATHODE	STYLE 12: PIN 1. 2. 3.	MAIN TERMINAL 1 GATE MAIN TERMINAL 2	STYLE 13: PIN 1. 2. 3.	ANODE 1 GATE CATHODE 2	STYLE 14: PIN 1. 2. 3.	EMITTER COLLECTOR BASE	STYLE 15: PIN 1. 2. 3.	ANODE 1 CATHODE ANODE 2
PIN 1. 2.	ANODE	PIN 1.	COLLECTOR BASE EMITTER	STYLE 18: PIN 1. 2. 3.	ANODE	STYLE 19: PIN 1. 2. 3.	GATE ANODE CATHODE	2.	NOT CONNECTED CATHODE ANODE
PINI 1	COLLECTOR EMITTER BASE	PIN 1.	SOURCE	PIN 1.	GATE	PIN 1. 2.	EMITTER	PIN 1. 2.	MT 1
	V _{CC} GROUND 2 OUTPUT	STYLE 27: PIN 1. 2. 3.	MT SUBSTRATE MT	2.	CATHODE ANODE GATE	2.	NOT CONNECTED ANODE CATHODE	2.	DRAIN GATE SOURCE
PIN 1. 2.	GATE DRAIN SOURCE	PIN 1.	BASE	PIN 1. 2.	RETURN INPUT OUTPUT	PIN 1. 2.	INPUT GROUND LOGIC		

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